TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74VCX2573FT, TC74VCX2573FK

Low-Voltage Octal D-Type Latch with 3.6-V Tolerant Inputs and Outputs

The TC74VCX2573 is a high-performance CMOS octal D-type latch. Designed for use in 1.8, 2.5 or 3.3 Volt systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

It is also designed with overvoltage tolerant inputs and outputs up to 3.6 V.

This 8 bit D-type latch is controlled by a latch enable input (LE) and an output enable input (\overline{OE}). When the \overline{OE} input is high, the eight outputs are in a high-impedance state. The 26- Ω series resistor helps reducing output overshoot and undershoot without external resistor.

All inputs are equipped with protection circuits against static discharge.

Features

- $26-\Omega$ series resistors on outputs.
- Low-voltage operation: $V_{CC} = 1.8$ to 3.6 V
- High-speed operation: $t_{pd} = 5.1 \text{ ns} (\text{max}) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$: $t_{rd} = 6.1 \text{ ns} (\text{max}) (V_{CC} = 2.3 \text{ to } 2.7 \text{ V})$

$$t_{pd} = 6.1 \text{ ns} (\text{max}) (\text{V}_{CC} = 2.3 \text{ to } 2.7 \text{ V})$$

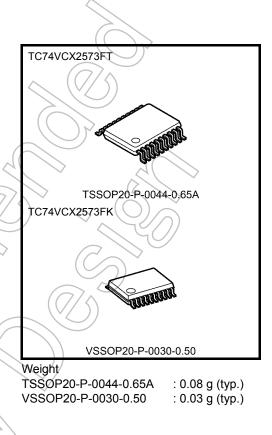
$$t_{pd} = 9.8 \text{ ns} (\text{max}) (\text{V}_{CC} = 1.8 \text{ V})$$

- Output current: $I_{OH}/I_{OL} = \pm 12 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
 - : $I_{OH}/I_{OL} = \pm 8 \text{ mA} \text{ (min)} (V_{CC} = 2.3 \text{ V})$

:
$$I_{OH}/I_{OL} = \pm 4 \text{ mA} \text{ (min)} (V_{CC} = 1.8 \text{ V})$$

- Latch-up performance: -300 mA
- ESD performance: Machine model $\geq \pm 200 \text{ V}$
 - Human body model ≥ ±2000 V
- Package: TSSOP and VSSOP (US)
- 3.6-V tolerant function and power-down protection provided on all inputs and outputs





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19

<u>18</u> Q1

17

16

15

14

13

- Q0

Q2

Q3

Q4

Q5

– Q6

<u>12</u> Q7

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Pin Assignment (top view)

IEC Logic Symbol

1

11

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3

4

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6

7

8

9

ΕN

>C1

1D

ŌĒ

LE

D0

D1

D2

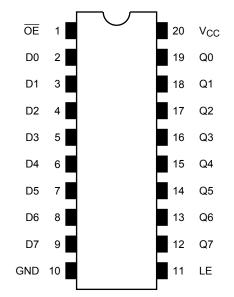
D3

D4

D5

D6

D7



Truth Table

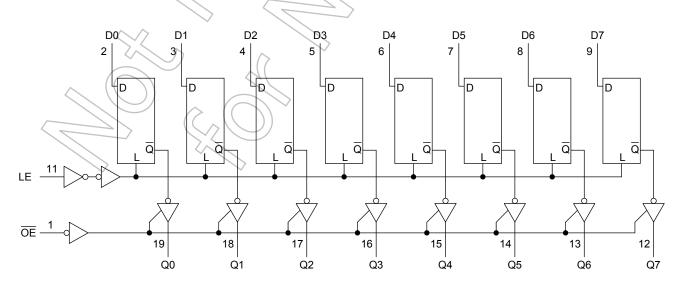
	Outputs		
ŌĒ	LE	D	Outputs
Н	Х	Х	z
L	L	Х	Qn
L	Н	L	
L	Н	Н	

X: Don't care

Z: High impedance

Qn: Q outputs are latched at the time when the LE input is taken to a low logic level.

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5 to 4.6	V	
DC input voltage	V _{IN}	-0.5 to 4.6	V	
		-0.5 to 4.6 (Note 2)	\sim	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)	V	\geq
Input diode current	I _{IK}	-50	mA	\bigcirc
Output diode current	I _{OK}	±50 (Note 4)	mA	
DC output current	I _{OUT}	±50	mA))
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 2: OFF state
- Note 3: High or low state. IOUT absolute maximum rating must be observed.
- Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	(V _{cc}	1.8 to 3.6	V
		1.2 to 3.6 (Note 2)	
Input voltage	VIN	-0.3 to 3.6	V
Output voltage	VOUT	0 to 3.6 (Note 3)	V
	V001	0 to V _{CC} (Note 4)	v
	~	±12 (Note 5)	
Output current	IOH/IOL	±8 (Note 6)	mA
\wedge (\bigcirc)		±4 (Note 7)	
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 8)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

- Note 2: Data retention only
- Note 3: OFF state
- Note 4: High or low state
- Note 5: $V_{CC} = 3.0$ to 3.6 V
- Note 6: V_{CC} = 2.3 to 2.7 V
- Note 7: V_{CC} = 1.8 V
- Note 8: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85° C, 2.7 V < V_{CC} \leq 3.6 V)

Characteris	stics	Symbol	Test C	ondition	V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	-	_	2.7 to 3.6	2.0	_	V
input voltage	L-level	VIL	-	_	2.7 to 3.6	1	0.8	v
				I _{OH} = -100 μA	2.7 to 3.6	V _{CC} - 0.2	_	
	H-level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I _{OH} = -6 mA	2.7	2.2		
				I _{OH} = -8 mA	3.0	2.4	_	V
Output voltage	Dutput voltage			I _{OH} = -12 mA	3.0	2.2	—	
			L VIN = VIH or VIL	I _{OL} = 100 μA	2.7 to 3.6		0.2	
	L-level	V _{OL}		I _{OL} = 6 mA	2.7	\mathcal{A}	0.4	-
	LIEVEI	VOL		I _{OL} = 8 mA	3.0	$\langle - \rangle$	0.55	
				I _{OL} ≠ 12 mA	3.0((0.8	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		2.7 to 3.6	Y)	±5.0	μA
3-state output OFF st	ate current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.7 to 3.6	(±10.0	μA
Power-off leakage cu	rrent	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V			—	10.0	μA
Quiescent supply current		laa	V _{IN} = V _{CC} or GND		2.7 to 3.6		20.0	
		ICC	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3.6 V$		2.7 to 3.6		±20.0	μA
Increase in I _{CC} per in	put	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6		750	

DC Characteristics (Ta = -40 to 85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Characteristi	cs	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIII		$\overline{\mathbf{x}}$	2.3 to 2.7	1.6	—	V
Input voltage	L-level	VIE			2.3 to 2.7	_	0.7	v
		>		I _{OH} = -100 μA	2.3 to 2.7	V _{CC} - 0.2	_	
\sim	H-level	Vон	VIN = VIH or VIL	I _{OH} = -4 mA	2.3	2.0	_	
	\sum		$\langle \rangle$	I _{OH} = -6 mA	2.3	1.8	—	v
Output voltage		\sim		I _{OH} = -8 mA	2.3	1.7	—	
)	VOL	VIN = VIH or VIL	I _{OL} = 100 μA	2.3 to 2.7	_	0.2	
	L-level			I _{OL} = 6 mA	2.3	_	0.4	
		2 > 2	9	I _{OL} = 8 mA	2.3	_	0.6	
Input leakage current	4	JIN	V _{IN} = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μA
3-state output OFF stat	e current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		2.3 to 2.7	_	±10.0	μA
Power-off leakage curre	ent	I _{OFF}	V _{IN} , V _{OUT} = 0 to 3.6 V		0	_	10.0	μA
Ouissest suggly suggest			V _{IN} = V _{CC} or GND		2.3 to 2.7	_	20.0	A
Quiescent supply curre	11L	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3$.6 V	2.3 to 2.7		±20.0	μA

DC Characteristics (Ta = -40 to 85°C, 1.8 V \leq V_{CC} < 2.3 V)

Characteristi	cs	Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
Input voltage	H-level	VIH	_	_	1.8 to 2.3	$0.7 \times V_{CC}$	_	V
Input voltage	L-level	VIL	-	_	1.8 to 2.3		$0.2 \times V_{CC}$	v
	H-level	Vон	VIN = VIH or VIL	I _{OH} = -100 μA	1.8	Vcc - 0.2	_	
Output voltage		011		$I_{OH} = -4 \text{ mA}$	71.8	1.4	_	V
	L-level	Vai	V_{OL} $V_{IN} = V_{IH} \text{ or } V_{IL}$	l _{OL} = 100 μA	1.8	_	0.2	
	L-level	VOL		$I_{OL} = 4 \text{ mA}$	1.8	_	0.3	
Input leakage current		I _{IN}	$V_{IN} = 0$ to 3.6 V		1.8		±5.0	μA
3-state output OFF sta	te current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \text{ to } 3.6 \text{ V}$		1.8	Â)	±10.0	μΑ
Power-off leakage curr	ent	I _{OFF}	V_{IN} , $V_{OUT} = 0$ to 3.6 V	(7)	0	$\leq -$	> 10.0	μA
Quippont quanty ourrent			$V_{IN} = V_{CC}$ or GND		1.8	J.F.	20.0	μA
Quiescent supply curre	71 L	Icc	$V_{CC} \le (V_{IN}, V_{OUT}) \le 3$.6 V	1.8	, P	±20.0	μ Λ

AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$) (Note 1)

Characteristics	Symbol	Test Condition		Min	Max	Unit
Characterietee	Cymbol		$V_{CC}(V)$			Onic
Propagation delay time	t		1.8	1.5	9.8	
(D-Q)	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	6.1	ns
	t _{pHL}		3.3 ± 0.3	0.6	5.1	
			1.8	1.5	9.8	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	6.3	ns
(LE-Q)	t _{pHL}	\sim ((3.3 ± 0.3	0.6	5.1	
			1.8	1.5	9.8	
3-state output enable time	t _{pZL}	Figure 1, Figure 3	2.5 ± 0.2	0.8	6.5	ns
	^t pZH		3.3 ± 0.3	0.6	5.0	
	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	1.8	1.5	7.7	ns
3-state output disable time			2.5 ± 0.2	0.8	4.3	
			3.3 ± 0.3	0.6	3.9	
			1.8	4.0	/ _	
Minimum pulse width (LE)	t _{w (H)}	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	ns
(LL)		$\langle \langle \rangle \rangle$ (3.3 ± 0.3	1.5	_	
			1.8	2.5		
Minimum set-up time	ts	Figure 1, Figure 2	2.5 ± 0.2	1.5	_	ns
			3.3 ± 0.3	1.5	_	
			1.8	1.0		
Minimum hold time	t _h	Figure 1, Figure 2	2.5 ± 0.2	1.0	_	ns
	6		$\textbf{3.3}\pm\textbf{0.3}$	1.0	_	
			1.8	_	0.5	
Output to output skew	tosLH	(Note 2)	2.5 ± 0.2	—	0.5	ns
	toshl		$\textbf{3.3}\pm\textbf{0.3}$	_	0.5	

Note 1: For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design. (tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
		$V_{IH} = 1.8 \ V, \ V_{IL} = 0 \ V$	(Note)	1.8	0.15	
Quiet output maximum dynamic V _{OL}	VOLP	$V_{IH} = 2.5 \text{ V}, \text{ V}_{IL} = 0 \text{ V}$	(Note)	2.5	0.25	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	0.35	
	V _{OLV}	$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	-0.15	v
Quiet output minimum dynamic V _{OL}		$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note)	2.5	-0.25	
02		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	-0.35	
Quiet output minimum dynamic V _{OH}	V _{OHV}	$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note)	1.8	1.55	
		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	2.5	2.05	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	(Note)	3.3	2.65	

Note: Parameter guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

			/		/	
Characteristics	Symbol	Test Condition	0	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}			1.8, 2.5, 3.3	6	pF
Output capacitance	C _{OUT}		(// s)	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz	(Note)	1.8, 2.5, 3.3	20	pF

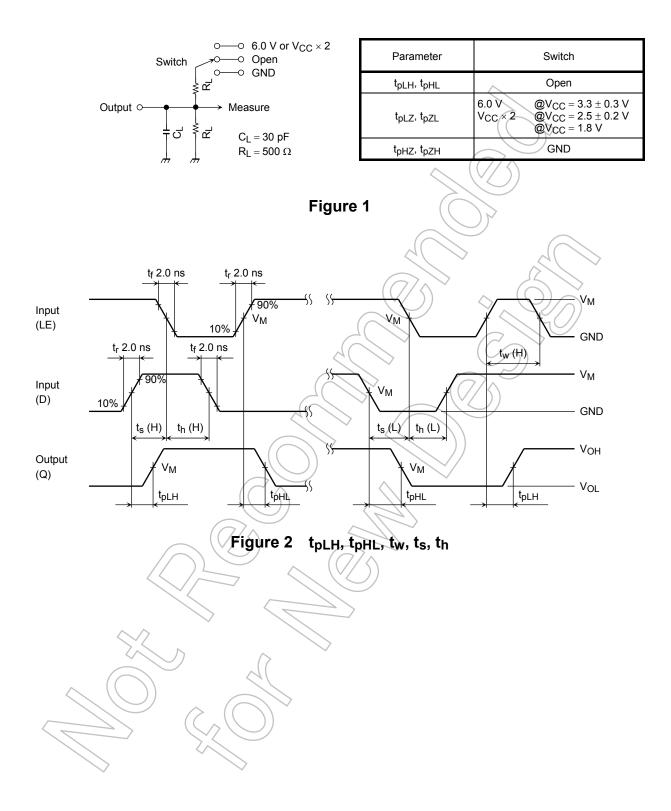
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

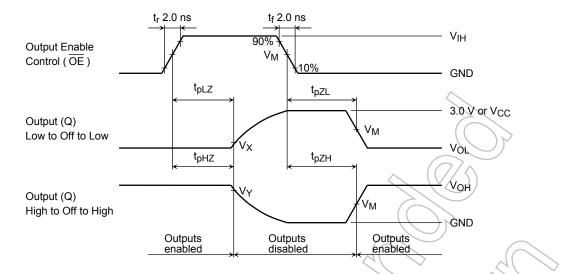
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

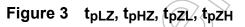
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AC Test Circuit



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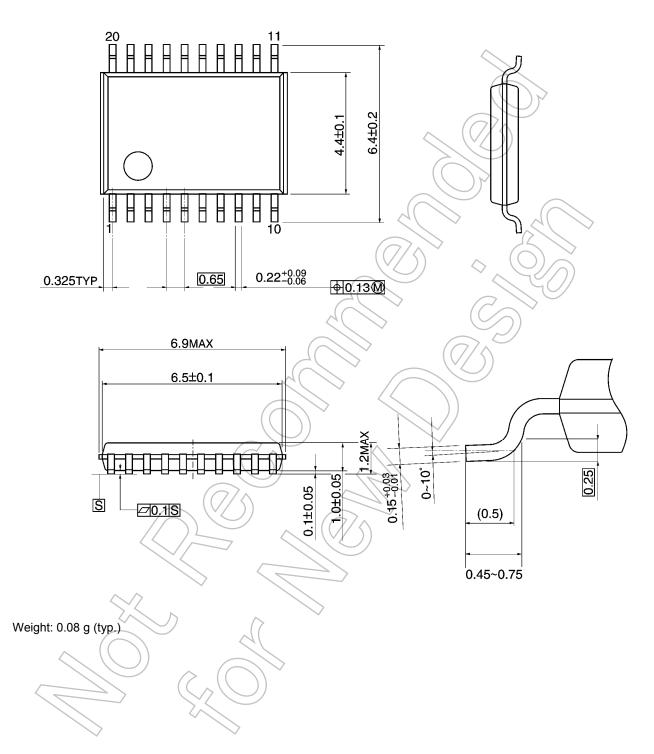
Symbol	Vcc							
Symbol —	$3.3\pm0.3~\text{V}$	2.5 ± 0.2 V	1.8 V					
V _{IH}	2.7 V	Vcc	v _{cc}					
VM	1.5 V	Vcc/2	Vcc/2					
V_{X}	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V					
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V					

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Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm

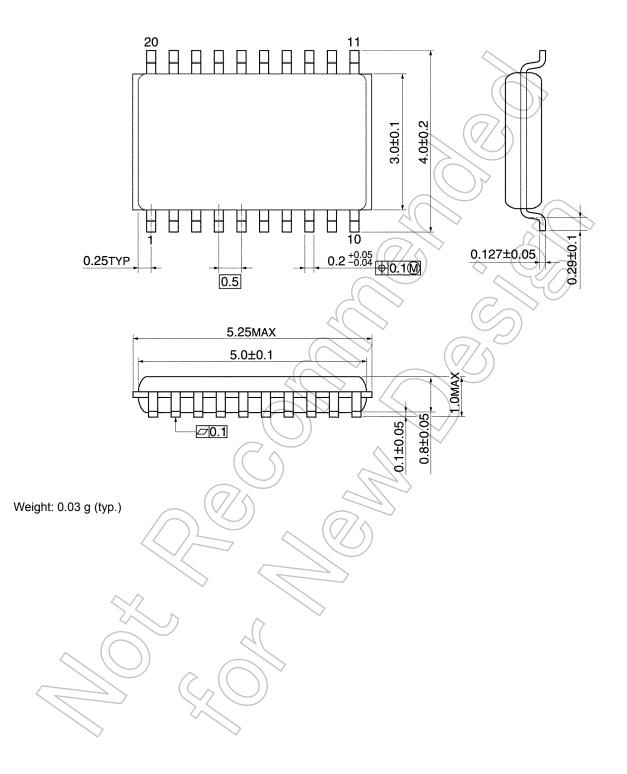




Package Dimensions

VSSOP20-P-0030-0.50

Unit: mm



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